

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC3607

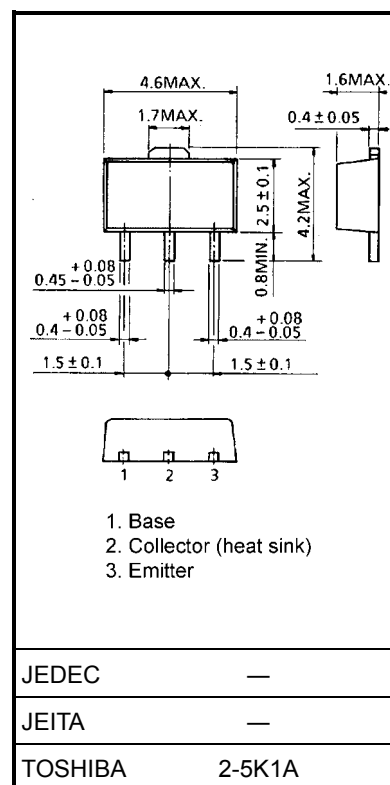
VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure, high gain.
- $NF = 1.1\text{dB}$, $|S_{21e}|^2 = 9.5\text{dB}$ ($f = 1\text{ GHz}$)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	20	V
Collector-emitter voltage	V_{CEO}	12	V
Emitter-base voltage	V_{EBO}	3	V
Base current	I_B	40	mA
Collector current	I_C	80	mA
Collector power dissipation	P_C	400	mW
		800 (Note 1)	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	$-55\sim 125$	$^\circ\text{C}$

Note 1: When mounted ceramic substrate of $250\text{ mm}^2 \times 0.8\text{ t}$ Microwave Characteristics ($T_a = 25^\circ\text{C}$)

Weight: 0.05 g (typ.)

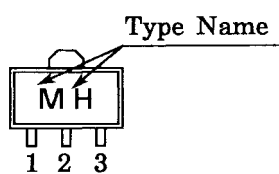
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition frequency	f_T	$V_{CE} = 10\text{ V}$, $I_C = 20\text{ mA}$	5	6.5	—	GHz
Insertion gain	$ S_{21e} ^2 (1)$	$V_{CE} = 10\text{ V}$, $I_C = 20\text{ mA}$, $f = 500\text{ MHz}$	—	15	—	dB
	$ S_{21e} ^2 (2)$	$V_{CE} = 10\text{ V}$, $I_C = 20\text{ mA}$, $f = 1\text{ GHz}$	6	9.5	—	
Noise figure	NF (1)	$V_{CE} = 10\text{ V}$, $I_C = 5\text{ mA}$, $f = 1\text{ GHz}$	—	1.1	—	dB
	NF (2)	$V_{CE} = 10\text{ V}$, $I_C = 40\text{ mA}$, $f = 1\text{ GHz}$	—	1.8	3	

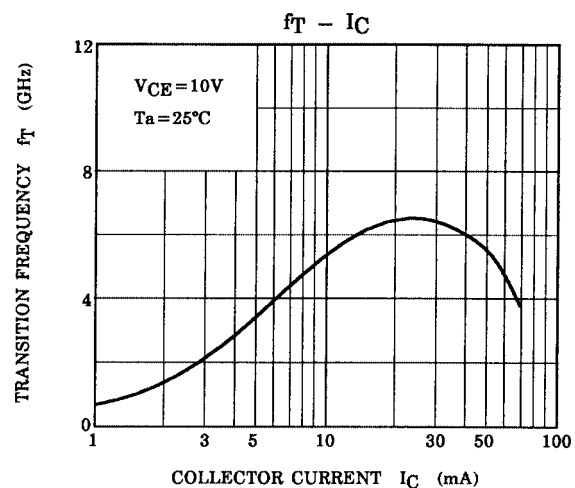
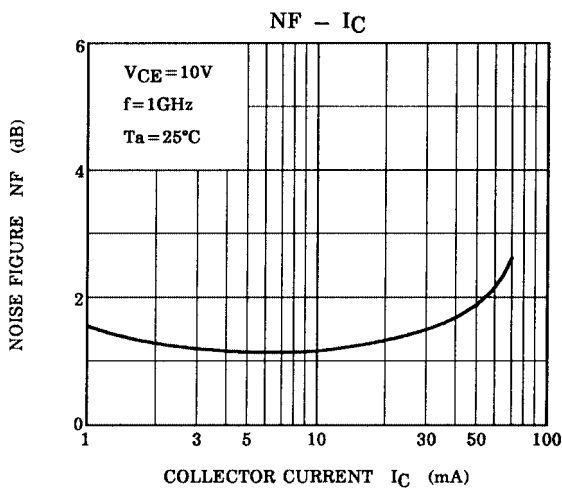
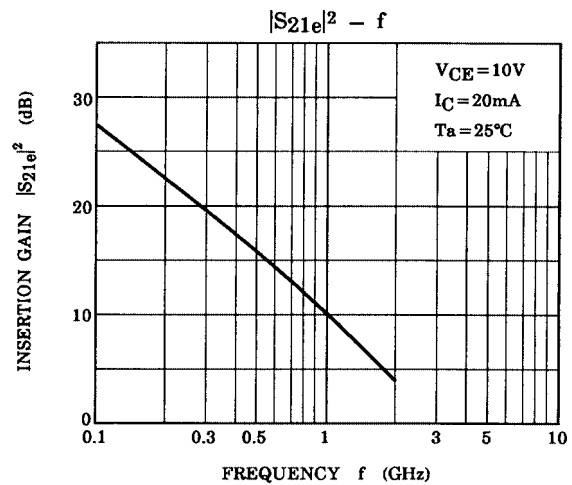
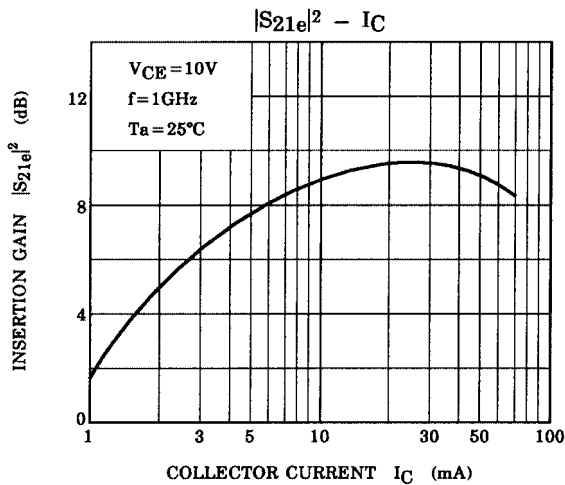
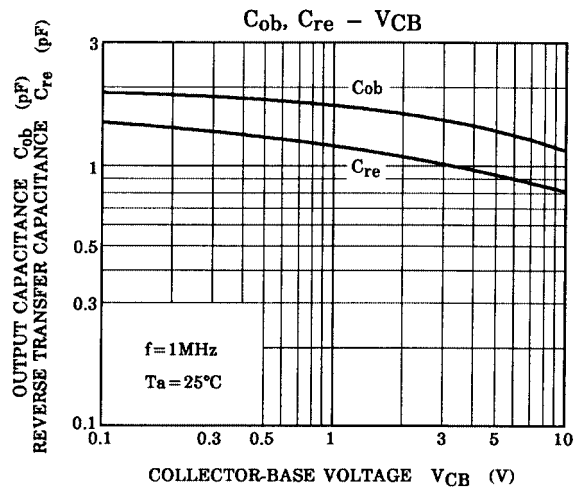
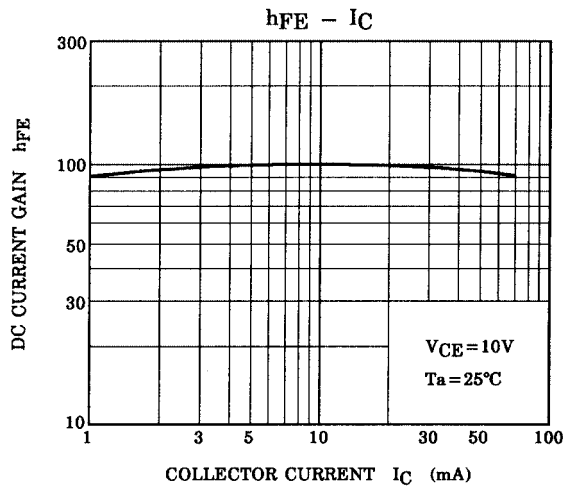
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

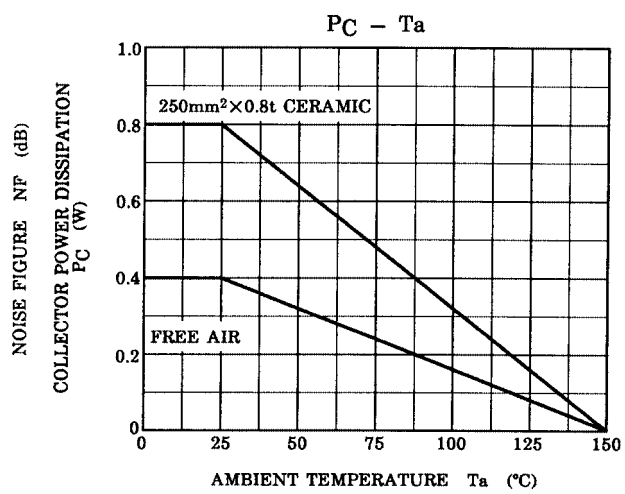
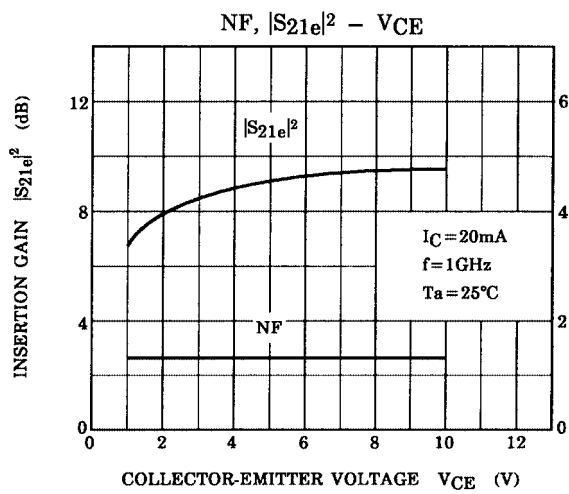
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 10\text{ V}$, $I_E = 0$	—	—	1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 1\text{ V}$, $I_C = 0$	—	—	1	μA
DC current gain	h_{FE}	$V_{CE} = 10\text{ V}$, $I_C = 20\text{ mA}$	30	—	250	
Collector output capacitance	C_{ob}	$V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$ (Note 2)	—	1.15	—	pF
Reverse transfer capacitance	C_{re}		—	0.8	1.25	pF

Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

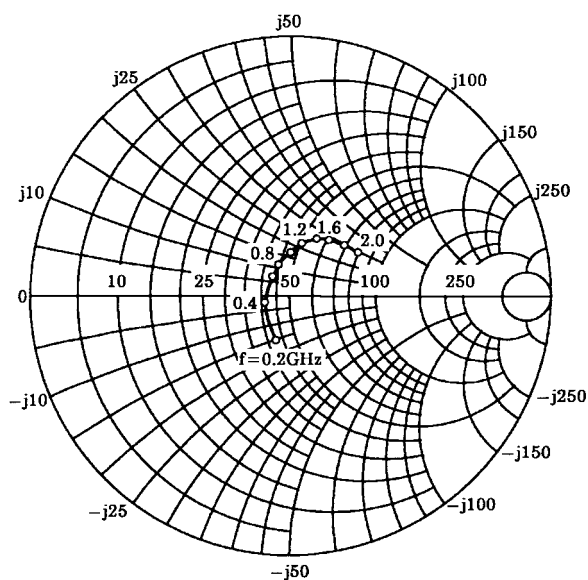
Marking



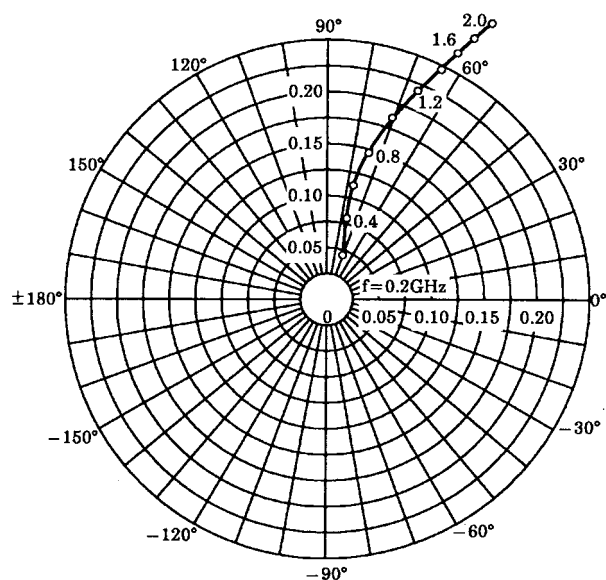




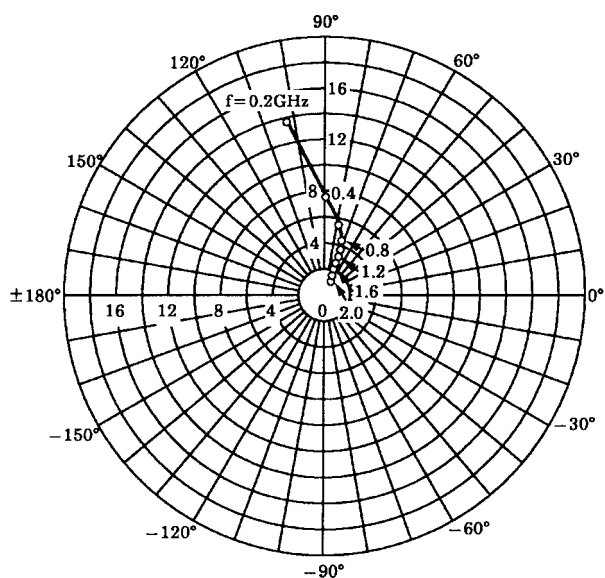
S_{11e}
 $V_{CE} = 10V$
 $I_C = 20mA$
 $T_a = 25^\circ C$
 (UNIT : Ω)



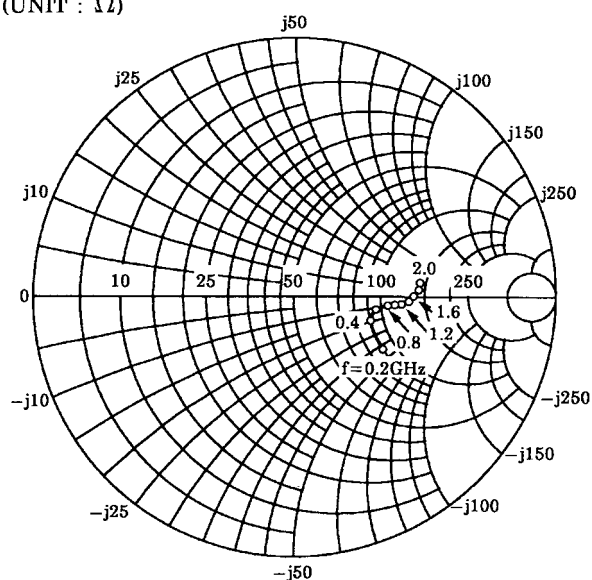
S_{12e}
 $V_{CE} = 10V$
 $I_C = 20mA$
 $T_a = 25^\circ C$



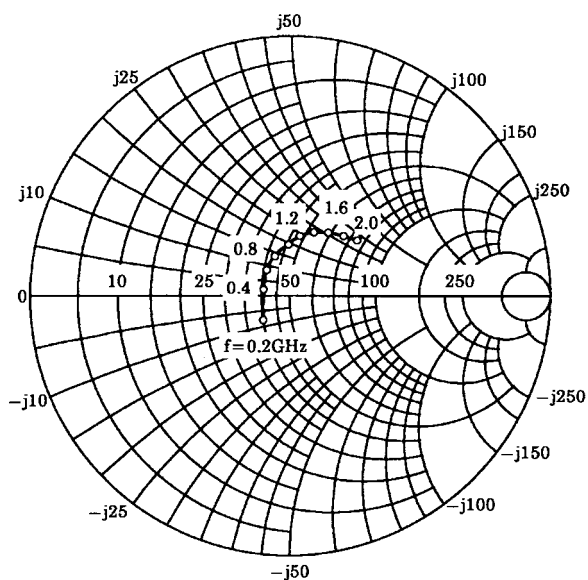
S_{21e}
 $V_{CE} = 10V$
 $I_C = 20mA$
 $T_a = 25^\circ C$



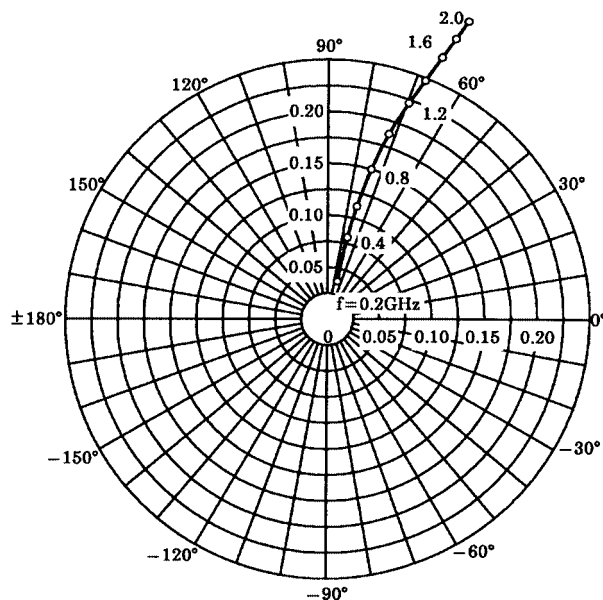
S_{22e}
 $V_{CE} = 10V$
 $I_C = 20mA$
 $T_a = 25^\circ C$
 (UNIT : Ω)



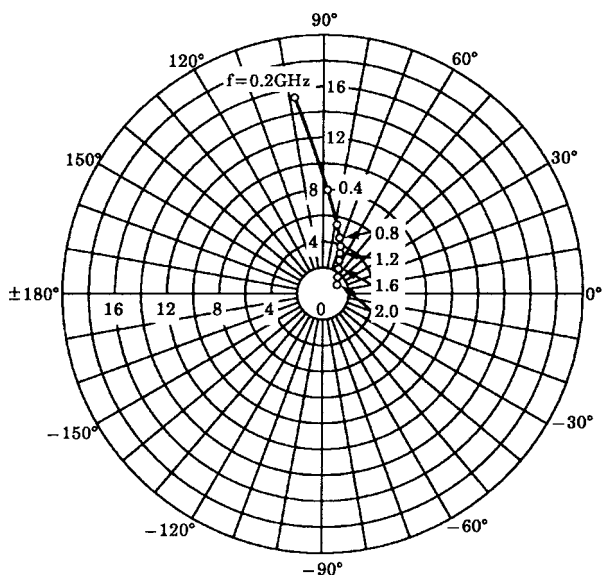
S_{11e}
 $V_{CE} = 10V$
 $I_C = 40mA$
 $T_a = 25^\circ C$
 (UNIT : Ω)



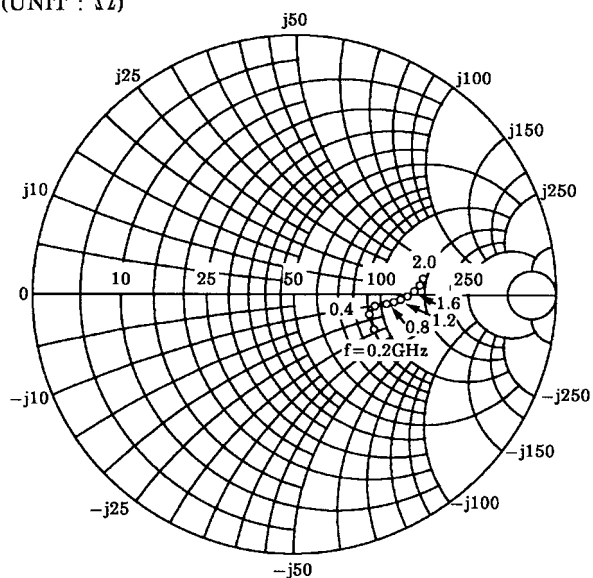
S_{12e}
 $V_{CE} = 10V$
 $I_C = 40mA$
 $T_a = 25^\circ C$



S_{21e}
 $V_{CE} = 10V$
 $I_C = 40mA$
 $T_a = 25^\circ C$



S_{22e}
 $V_{CE} = 10V$
 $I_C = 40mA$
 $T_a = 25^\circ C$
 (UNIT : Ω)



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